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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Chich Shang CHANG et al

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Art Unit: 2823

Title: METHOD FOR FORMING A SINGLE-CRYSTAL SILICON LAYER ON A
TRANSPARENT SUBSTRATE

Date: January 25, 2006

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Commissioner for Patents
P.O. Box 1450
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RESPONSE COVER SHEET

Sir:

Attached hereto please find a response to the Office Action mailed on October 31,
2005.

No fee is believed to be due in connection with the filing of this paper. If, however, the
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